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### FAIRCHILD

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### FDS2572

### 150V, 0.047 Ohms, 4.9A, N-Channel UltraFET<sup>®</sup> Trench MOSFET

#### **General Description**

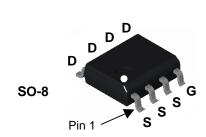
UltraFET<sup>®</sup> devices combine characteristics that enable benchmark efficiency in power conversion applications. Optimized for Rds(on), low ESR, low total and Miller gate charge, these devices are ideal for high frequency DC to DC converters.

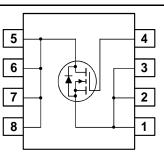
#### Applications

- DC/DC converters
- Telecom and Data-Com Distributed Power Architectures
- 48-volt I/P Half-Bridge/Full-Bridge
- 24-volt Forward and Push-Pull topologies

#### Features

- $R_{DS(ON)} = 0.040\Omega$  (Typ.),  $V_{GS} = 10V$
- $Q_{g(TOT)} = 29nC (Typ.), V_{GS} = 10V$
- Low Q<sub>RR</sub> Body Diode
- Maximized efficiency at high frequencies
- UIS Rated





**MOSFET Maximum Ratings**  $T_A=25^{\circ}C$  unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage	150	V	
V <sub>GS</sub>	Gate to Source Voltage	±20	V	
I <sub>D</sub>	Drain Current			
	Continuous (T <sub>C</sub> = 25°C, V <sub>GS</sub> = 10V, $R_{\theta JA}$ = 50 °C/W)	4.9	Α	
	Continuous (T <sub>C</sub> = 100°C, V <sub>GS</sub> = 10V, $R_{\theta JA}$ = 50 °C/W)	3.1	А	
	Pulsed	Figure 4	А	
P <sub>D</sub>	Power dissipation	2.5	W	
	Derate above 25°C	20	mW/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to 150	°C	

#### **Thermal Characteristics**

$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case	(NOTE1)	25	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Case at 10 seconds	(NOTE2)	50	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Case at steady state	(NOTE2)	85	°C/W

### Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS2572	FDS2572	330mm	12mm	2500units

FDS2572

July 2013

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	octeristics					
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	150	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 120V$ $V_{GS} = 0V$ $T_{C} = 150^{\circ}C$	-	-	1 250	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>GS</sub> = ±20V	-	-	±100	nA
On Chara	cteristics					
V <sub>GS(TH)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	-	4	V
r <sub>DS(ON)</sub>	Drain to Source On Resistance	$I_{\rm D} = 4.9$ A, $V_{\rm GS} = 10$ V	-	0.040	0.047	Ω
r <sub>DS(ON)</sub>	Drain to Source On Resistance	I <sub>D</sub> = 4.9A, V <sub>GS</sub> = 6V	-	0.044	0.053	Ω
Dynamic	Characteristics					
C <sub>ISS</sub>	Input Capacitance		-	2050	2870	pF
C <sub>OSS</sub>	Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ = 1MHz	-	220	310	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		-	48	80	pF
R <sub>g</sub>	Gate Resistance		0.1	1.3	3.0	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0V to 10V	-	29	38	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS} = 0V \text{ to } 2V$ $V_{DD} = 75V$	-	4	6	nC
Q <sub>gs</sub>	Gate to Source Gate Charge	$I_D = 4.9A$ $I_a = 1.0mA$	-	8	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge		-	6	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau		-	4	-	nC
Switching	g Characteristics					
t <sub>ON</sub>	Turn-On Time		-	-	27	ns
t <sub>d(ON)</sub>	Turn-On Delay Time		-	14	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 75V, I <sub>D</sub> = 4.9A	-	4	-	ns
t <sub>d(OFF)</sub>	Turn-Off Delay Time	$V_{GS} = 10V, R_G = 10\Omega$	-	44	-	ns
t <sub>f</sub>	Fall Time		-	22	-	ns
t <sub>OFF</sub>	Turn-Off Time		-	-	100	ns
Drain-Sou	urce Diode Characteristics					
\/	Source to Droip Diade Maltara	I <sub>SD</sub> = 4.9A	-	-	1.25	V
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 3.1A	-	-	1.0	V
t <sub>rr</sub>	Reverse Recovery Time	$I_{SD} = 4.9A, dI_{SD}/dt = 100A/\mu s$	-	-	72	ns
Q <sub>RR</sub>	Reverse Recovered Charge	I <sub>SD</sub> = 4.9, dI <sub>SD</sub> /dt =100A/μs	-	-	158	nC

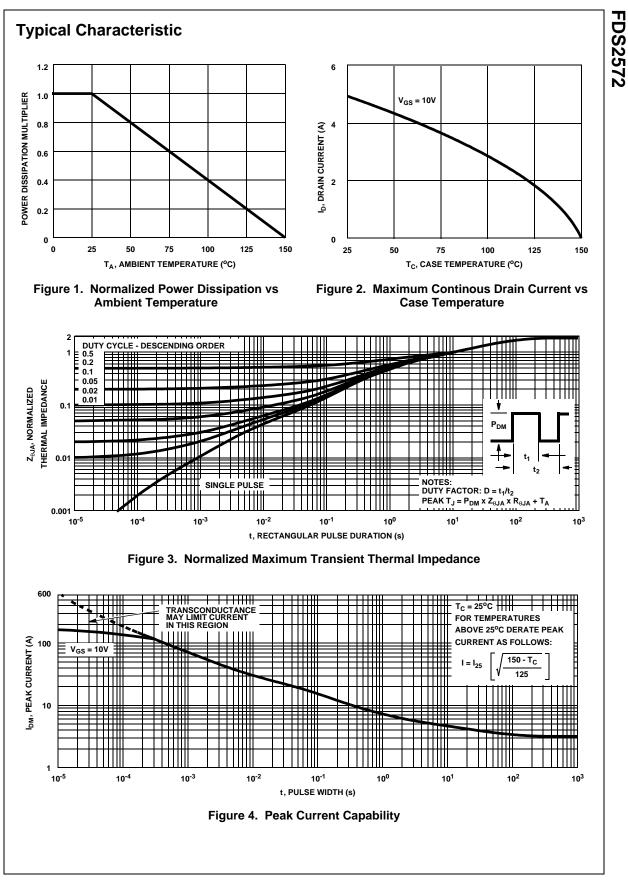
Notes:

1.  $R_{\text{RJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal referance is defined as the solder mounting surface of the drain pins.  $R_{\text{RJC}}$  is guaranteed by design while  $R_{\text{RCA}}$  is determined by the user's board design.

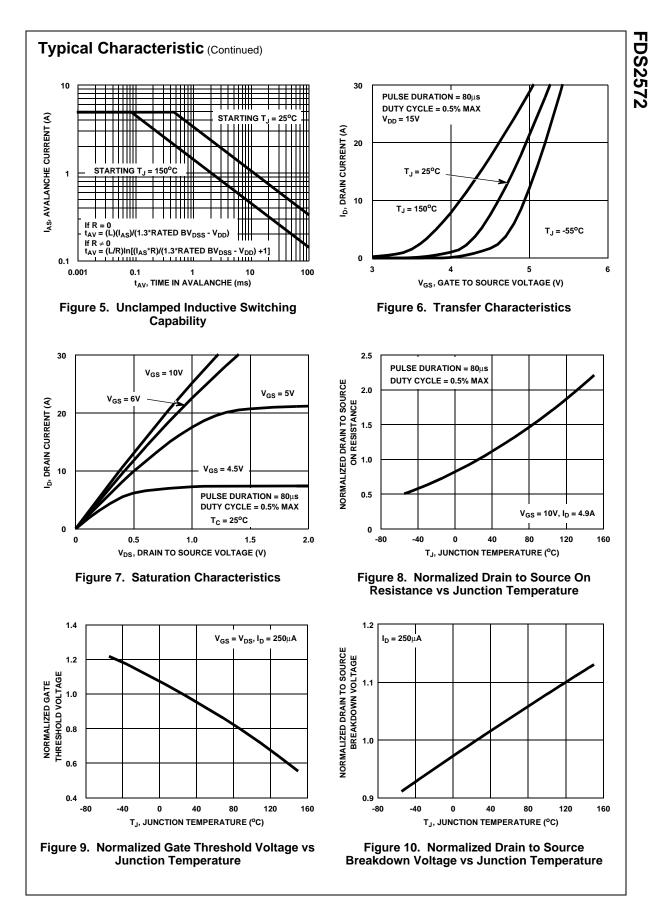
2.  $R_{\theta JA}$  is measured with 1.0in  $^2\,$  copper on FR-4 board

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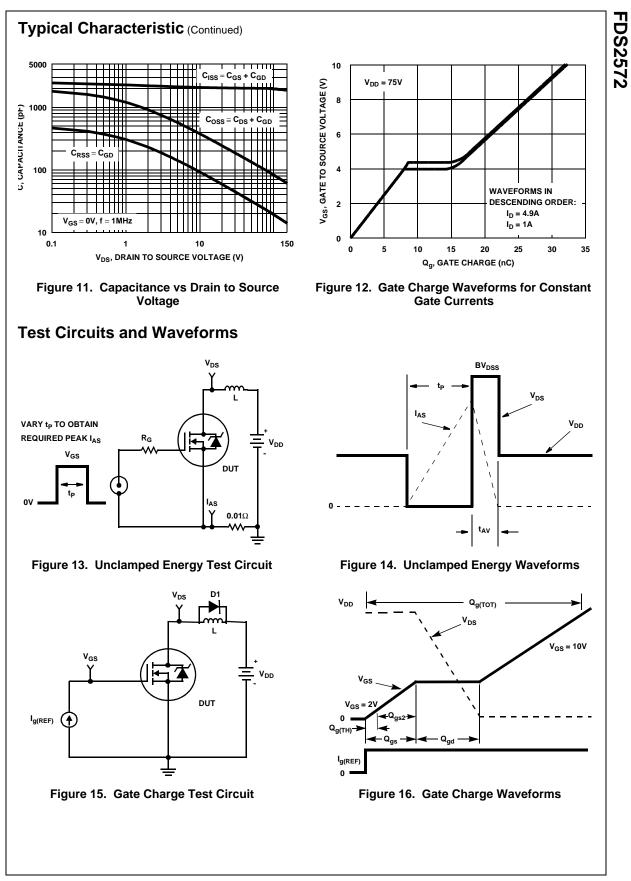


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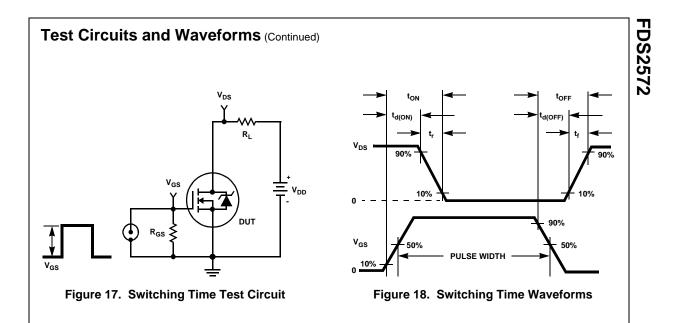


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#### Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T<sub>IM</sub>, and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P<sub>DM</sub>, in an application. Therefore the application's ambient temperature, T<sub>A</sub> (<sup>o</sup>C), and thermal resistance  $R_{\theta JA}$  (°C/W) must be reviewed to ensure that T<sub>JM</sub> is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the SO8 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of PDM is complex and influenced by many factors:

- 1. Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 19 defines the  $\mathsf{R}_{\theta \mathsf{J}\mathsf{A}}$  for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually

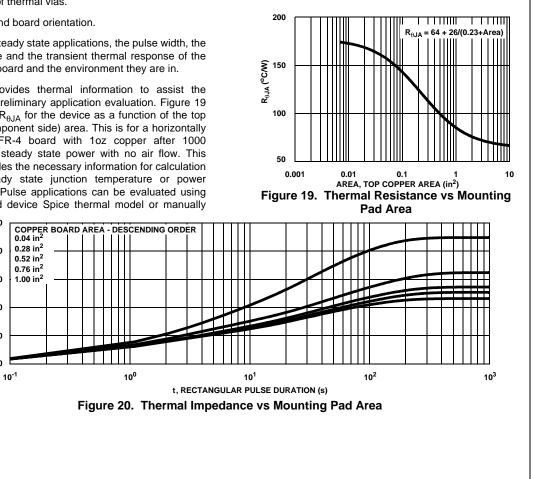
utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 19 or by calculation using Equation 2. The area, in square inches is the top copper area including the gate and source pads.

$$R_{\theta JA} = 64 + \frac{26}{0.23 + Area}$$
(EQ. 2)

The transient thermal impedance ( $Z_{\theta JA}$ ) is also effected by varied top copper board area. Figure 20 shows the effect of copper pad area on single pulse transient thermal impedance. Each trace represents a copper pad area in square inches corresponding to the descending list in the graph. Spice and SABER thermal models are provided for each of the listed pad areas.

Copper pad area has no perceivable effect on transient thermal impedance for pulse widths less than 100ms. For pulse widths less than 100ms the transient thermal impedance is determined by the die and package. Therefore, CTHERM1 through CTHERM5 and RTHERM1 through RTHERM5 remain constant for each of the thermal models. A listing of the model component values is available in Table 1.



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120

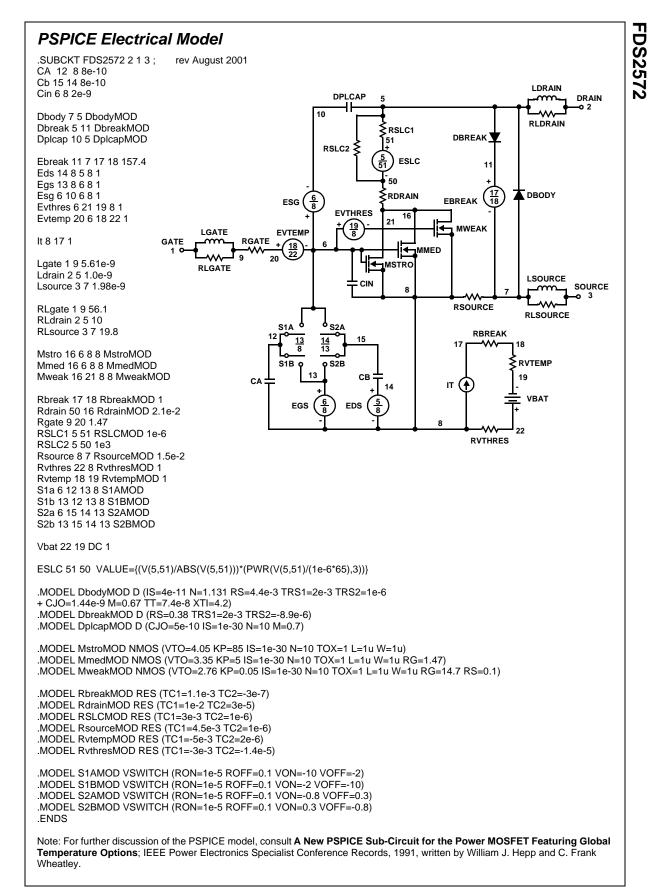
90

60

30

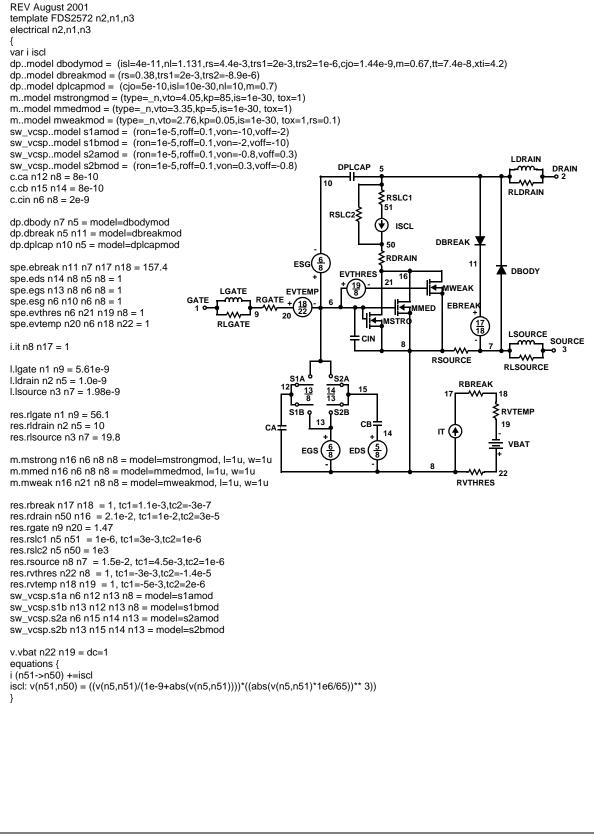
0

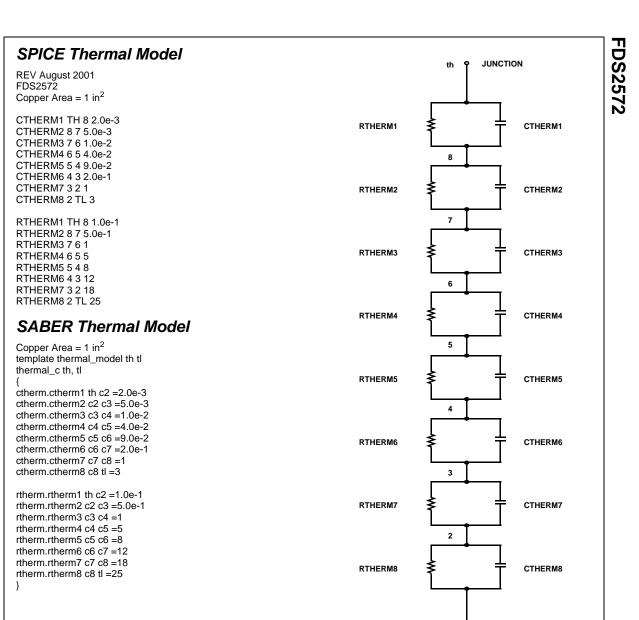
Z<sub>0JA</sub>, THERMAL IMPEDANCE (°C/W)



FDS2572

#### SABER Electrical Model





#### TABLE 1. THERMAL MODELS

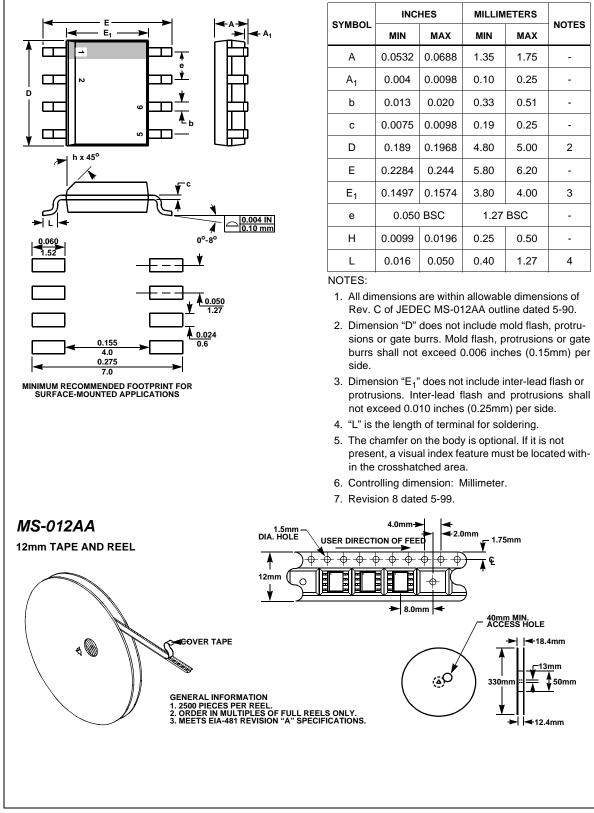
0.04 in <sup>2</sup>	0.28 in <sup>2</sup>	0.52 in <sup>2</sup>	0.76 in <sup>2</sup>	1.0 in <sup>2</sup>
1.2e-1	1.5e-1	2.0e-1	2.0e-1	2.0e-1
0.5	1.0	1.0	1.0	1.0
1.3	2.8	3.0	3.0	3.0
26	20	15	13	12
39	24	21	19	18
55	38.7	31.3	29.7	25
	1.2e-1 0.5 1.3 26 39	1.2e-1 1.5e-1   0.5 1.0   1.3 2.8   26 20   39 24	1.2e-1     1.5e-1     2.0e-1       0.5     1.0     1.0       1.3     2.8     3.0       26     20     15       39     24     21	1.2e-1     1.5e-1     2.0e-1     2.0e-1       0.5     1.0     1.0     1.0       1.3     2.8     3.0     3.0       26     20     15     13       39     24     21     19

CASE

tl

### **MS-012AA**

8 LEAD JEDEC MS-012AA SMALL OUTLINE PLASTIC PACKAGE



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